

December 2009

FDMC7660 N-Channel PowerTrench[®] MOSFET 30 V, 20 A, 2.2 m Ω

Features

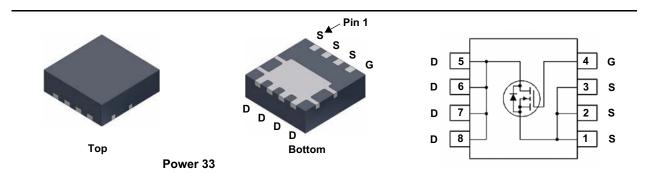
- Max $r_{DS(on)}$ = 2.2 m Ω at V_{GS} = 10 V, I_D = 20 A
- Max $r_{DS(on)}$ = 3.3 m Ω at V_{GS} = 4.5 V, I_D = 18 A
- High performance technology for extremely low r_{DS(on)}
- Termination is Lead-free and RoHS Compliant

General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench[®] process that has been especially tailored to minimize the on-state resistance. This device is well suited for Power Management and load switching applications common in Notebook Computers and Portable Battery Packs.

Applications

- DC DC Buck Converters
- Point of Load
- High Efficiency Load Switch and Low Side Switching



MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			30	V	
V _{GS}	Gate to Source Voltage		(Note 4)	±20	V	
	Drain Current -Continuous (Package limited)	T _C = 25°C		40		
I _D	-Continuous (Silicon limited)	T _C = 25°C		100	٨	
	-Continuous	T _A = 25°C	(Note 1a)	20	— A	
	-Pulsed			200		
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	200	mJ	
D	Power Dissipation	T _C = 25°C		41	14/	
P _D	Power Dissipation	T _A = 25°C	(Note 1a)	2.3	W	
T _J , T _{STG}	Operating and Storage Junction Temperature R	Operating and Storage Junction Temperature Range		-55 to + 150	°C	

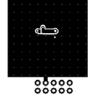
Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	3	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient (Note 1a)	53	0/00

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC7660	FDMC7660	Power 33	13"	12 mm	3000 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	acteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25°C		14		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 24 V, V _{GS} = 0 V			1	μA
I _{GSS}	Gate to Source Leakage Current	V_{GS} = 20 V, V_{DS} = 0 V			100	nA
On Chara	acteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250 μA	1.2	1.7	2.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25°C		-6		mV/°C
		V _{GS} = 10 V, I _D = 20 A		1.8	2.2	
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 4.5 V, I _D = 18 A		2.6	3.3	mΩ
		V _{GS} = 10 V, I _D = 20 A, T _J = 125°C		2.2	3.1	
9 _{FS}	Forward Transconductance	$V_{DS} = 5 V, I_{D} = 20 A$		163		S
	Characteristics			2020	4020	- 5
C _{iss}				3630	4830	рF
C _{oss}	Output Capacitance Reverse Transfer Capacitance	f = 1MHz		1345 110	1790 165	pF pF
C _{rss}	Gate Resistance			0.9	105	Ω
R _g Switching	g Characteristics			0.9		52
t _{d(on)}	Turn-On Delay Time			14	25	ns
t _r	Rise Time	V _{DD} = 15 V, I _D = 20 A,		6.8	14	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		36	58	ns
t _f	Fall Time			5.7	11	ns
Q _g	Total Gate Charge	$V_{GS} = 0 V \text{ to } 10 V$		54	86	nC
Q _g	Total Gate Charge	$V_{GS} = 0 V \text{ to } 4.5 V$ $V_{DD} = 15 V$, $I_D = 20 A$		24	38	nC
Q _{gs}	Gate to Source Charge	I _D = 20 A		11		nC
Q _{gd}	Gate to Drain "Miller" Charge			5.6		nC
Drain-So	urce Diode Characteristics					
V _{SD}	Source-Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 20 A$ (Note 2)		0.8	1.2	v
▼SD	Source-Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 1.9 A$ (Note 2)		0.7	1.2	v
t _{rr}	Reverse Recovery Time	I _F = 20 A, di/dt = 100 A/μs		45	63	ns
Q _{rr}	Reverse Recovery Charge			25	35	nC



. 53°C/W when mounted on a 1 in² pad of 2 oz copper

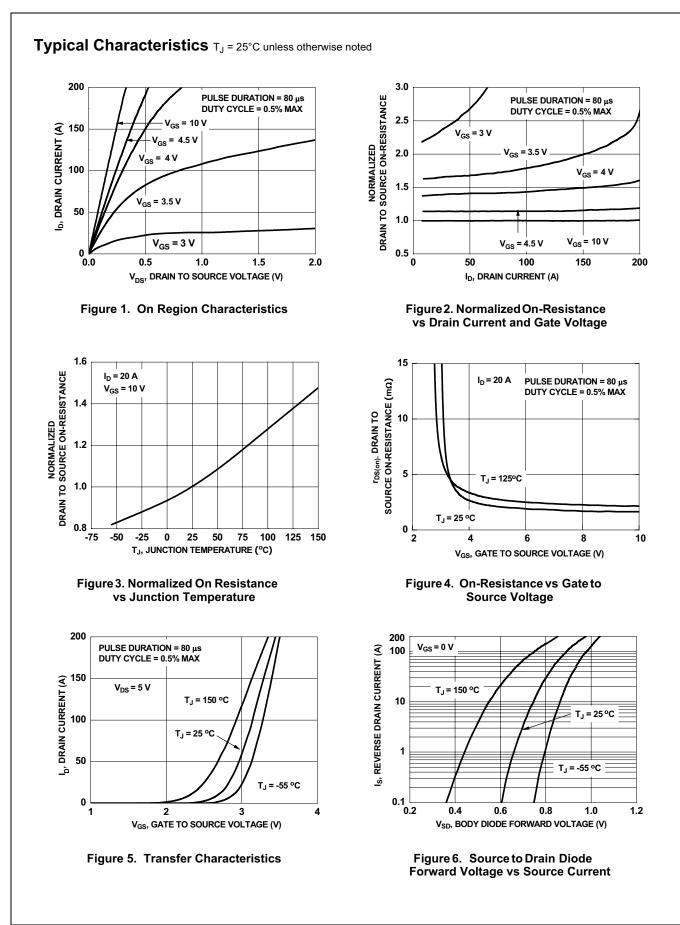
b. 125°C/W when mounted on a minimum pad of 2 oz copper



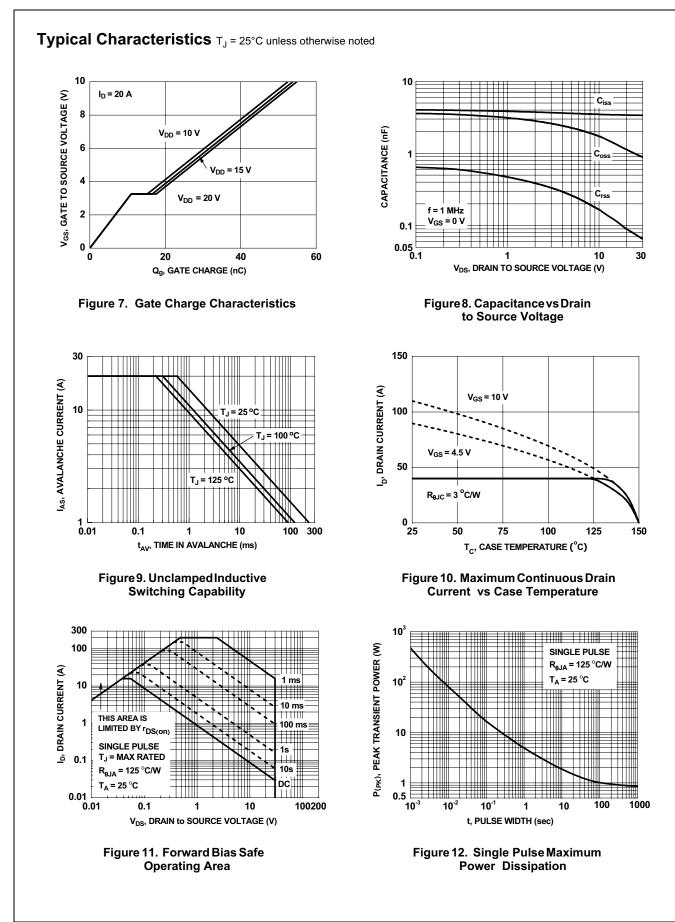
2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0%.

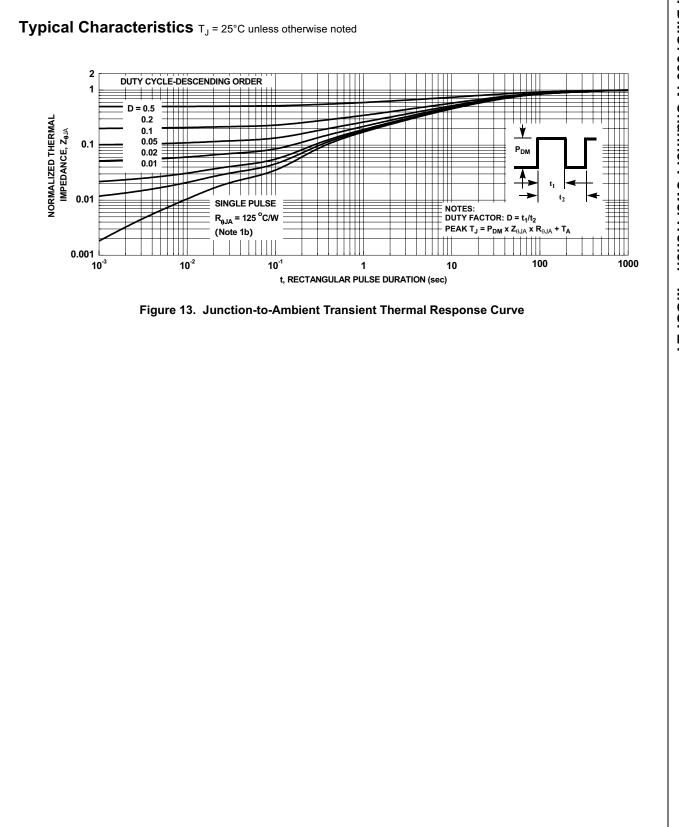
3. Starting T_J = 25 °C, L = 1 mH, I_{AS} = 20 A, V_{DD} = 27 V, V_{GS} = 10 V

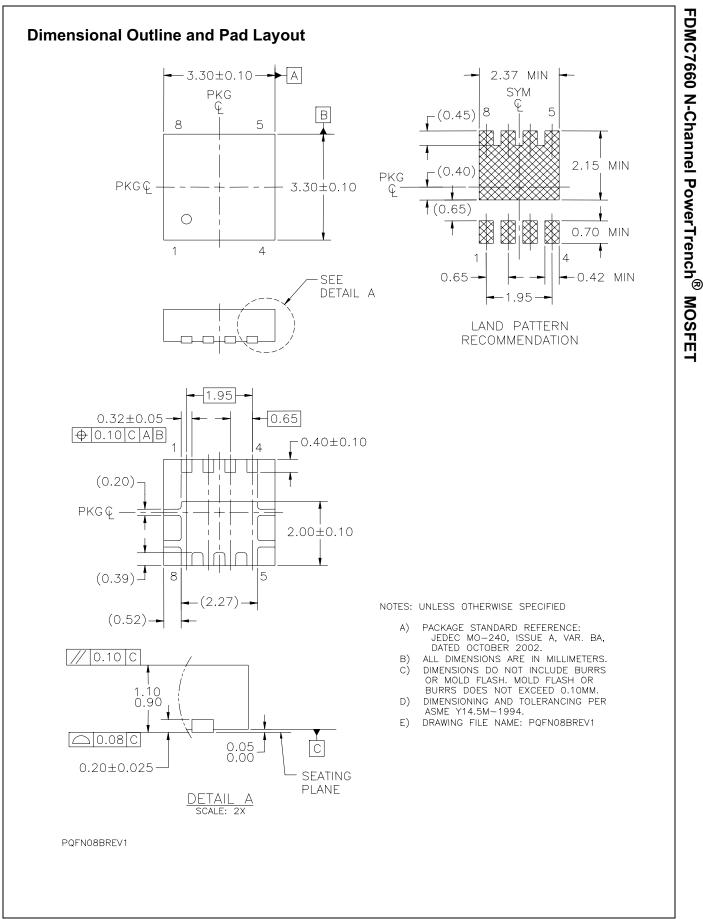
4. As an N-channel device, the negative Vgs rating is for low duty cycle pulse ocurrence only. No continuous rating is implied













SEMICONDUCTOR

TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower™	FlashWriter [®] *	Power-SPM™_
Auto-SPM™	FPS™	PowerTrench [®]
Build it Now™	F-PFS™	PowerXS™
CorePLUS™	FRFET®	Programmable Active Droop™
CorePOWER™	Global Power Resource SM	QFET®
CROSSVOLT™	Green FPS™	QS™
CTL™	Green FPS™ e-Series™	Quiet Series™
Current Transfer Logic™	Gmax™	RapidConfigure™
DEUXPEED®	GTO™	\sim
Dual Cool™_	IntelliMAX™	M
EcoSPARK [®]	ISOPLANAR™	Saving our world, 1mW/W/kW at a tim
EfficentMax™	MegaBuck™	SignalWise™
EZSWITCH™*	MICROCOUPLER™	SmartMax™
TM*	MicroFET™	SMART START™
	MicroPak™	SPM®
F ®	MillerDrive™	STEALTH™
†	MotionMax™	SuperFET™
Fairchild®	Motion-SPM™_	SuperSOT™-3
Fairchild Semiconductor [®]	OPTOLOGIC®	SuperSOT™-6
FACT Quiet Series™	OPTOPLANAR®	SuperSOT™-8
FACT [®]	®	SupreMOS [™]
FAST [®]		SyncFET™
FastvCore™	PDP SPM™	Sync-Lock™
FETBench™	FDF SFMI	

TinyCalc™ TinyLogic® TINYOPTO™ ne™ TinyPower™ TinyPWM™ TinyWire™ TriFault Detect™ TRUECURRENT™* μSerDes™ $\mu_{_{\mathrm{Ser}}}$



GENERAL ® The Power Franchise[®]

Jwer franchise TinyBoost™ TinyBuck™

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN WHICH COVERS THESE PRODUCTS

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- Life support devices or systems are devices or systems which, (a) are 1. intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or 2. system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS Definition of Terms

Advance information Formative / in Design may change in any manner without notice. Preliminary First Production Datasheet contains preliminary data; supplementary data will be published at a l date. Fairchild Semiconductor reserves the right to make changes at any time w notice to improve design. No Identification Needed Full Production Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design. Observed. Not the Design during Datasheet contains specifications on a product that is discontinued by Fairchild	Datasheet Identification	Product Status	Definition
Preliminary First Production date. Fairchild Semiconductor reserves the right to make changes at any time w notice to improve design. No Identification Needed Full Production Datasheet contains final specifications. Fairchild Semiconductor reserves the rig make changes at any time without notice to improve the design. Obscience Not the Deschation Datasheet contains specifications on a product that is discontinued by Fairchild	Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Notice for the base of the base	Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
Obsolute Not In Production Datasheet contains specifications on a product that is discontinued by Fairchild	No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Semiconductor. The datasheet is for reference information only.	Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.